# DISCRETE SEMICONDUCTORS



Product specification Supersedes data of 1999 Jul 23



## **BGA2003**

#### FEATURES

- · Low current
- Very high power gain
- Low noise figure
- Integrated temperature compensated biasing
- · Control pin for adjustment bias current
- Supply and RF output pin combined.

#### **APPLICATIONS**

- RF front end
- Wideband applications, e.g. analog and digital cellular telephones, cordless telephones (PHS, DECT, etc.)
- · Low noise amplifiers
- Satellite television tuners (SATV)
- High frequency oscillators.

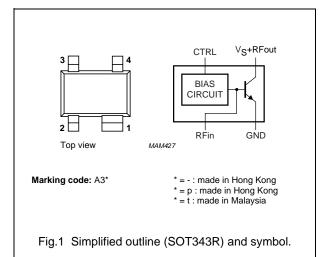
QUICK REFERENCE DATA

#### DESCRIPTION

Silicon MMIC amplifier consisting of an NPN double polysilicon transistor with integrated biasing for low voltage applications in a plastic, 4-pin SOT343R package.

#### PINNING

PIN	DESCRIPTION	
1	GND	
2	RF in	
3	CTRL (bias current control)	
4	V <sub>S</sub> + RF out	



SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
V <sub>S</sub>	DC supply voltage	RF input AC coupled	-	4.5	V
ا <sub>S</sub>	DC supply current	V <sub>VS-OUT</sub> = 2.5 V; I <sub>CTRL</sub> = 1 mA; RF input AC coupled	11	-	mA
MSG	maximum stable gain	V <sub>VS-OUT</sub> = 2.5 V; f = 1800 MHz; T <sub>amb</sub> = 25 °C	16	_	dB
NF	noise figure	$V_{VS-OUT}$ = 2.5 V; f = 1800 MHz; $\Gamma_S = \Gamma_{opt}$	1.8	-	dB

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## LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Vs	supply voltage	RF input AC coupled	-	4.5	V
V <sub>CTRL</sub>	voltage on control pin		-	2	V
I <sub>S</sub>	supply current (DC)	forced by DC voltage on RF input or I <sub>CTRL</sub>	-	30	mA
I <sub>CTRL</sub>	control current		-	3	mA
P <sub>tot</sub>	total power dissipation	$T_s \le 100 \ ^\circ C$	-	135	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	operating junction temperature		-	150	°C

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	VALUE	UNIT
R <sub>th j-s</sub>	thermal resistance from junction to soldering point	350	K/W

## CHARACTERISTICS

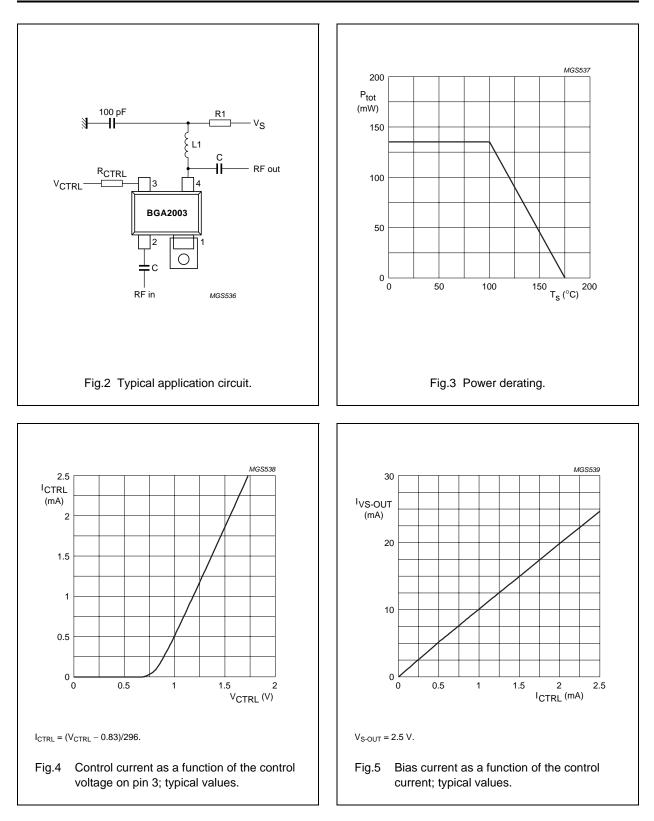
RF input AC coupled;  $T_i = 25 \text{ °C}$ ; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I <sub>S</sub>	supply current	V <sub>VS-OUT</sub> = 2.5 V; I <sub>CTRL</sub> = 0.4 mA	3	4.5	6	mA
		$V_{VS-OUT} = 2.5 V; I_{CTRL} = 1.0 mA$	8	11	15	mA
MSG	maximum stable gain	V <sub>VS-OUT</sub> = 2.5 V; I <sub>VS-OUT</sub> = 10 mA; f = 900 MHz	-	24	-	dB
		V <sub>VS-OUT</sub> = 2.5 V; I <sub>VS-OUT</sub> = 10 mA; f = 1800 MHz	-	16	-	dB
$ s_{21} ^2$	insertion power gain	V <sub>VS-OUT</sub> = 2.5 V; I <sub>VS-OUT</sub> = 10 mA; f = 900 MHz	18	19	-	dB
		V <sub>VS-OUT</sub> = 2.5 V; I <sub>VS-OUT</sub> = 10 mA; f = 1800 MHz	13	14	-	dB
s <sub>12</sub>	isolation	V <sub>VS-OUT</sub> = 2.5 V; I <sub>VS-OUT</sub> = 0; f = 900 MHz	-	26	-	dB
		V <sub>VS-OUT</sub> = 2.5 V; I <sub>VS-OUT</sub> = 0; f = 1800 MHz	-	20	-	dB
NF	noise figure	$V_{VS-OUT}$ = 2.5 V; $I_{VS-OUT}$ = 10 mA; f = 900 MHz; $\Gamma_S = \Gamma_{opt}$	-	1.8	2	dB
		$V_{VS-OUT}$ = 2.5 V; $I_{VS-OUT}$ = 10 mA; f = 1800 MHz; $\Gamma_S = \Gamma_{opt}$	-	1.8	2	dB
IP3 <sub>(in)</sub>	input intercept point; note 1	V <sub>VS-OUT</sub> = 2.3 V; I <sub>VS-OUT</sub> = 3.6 mA; f = 900 MHz	-	-6.5	-	dBm
		$V_{VS-OUT}$ = 2.3 V; $I_{VS-OUT}$ = 3.5 mA; f = 1800 MHz	-	-4.8	-	dBm

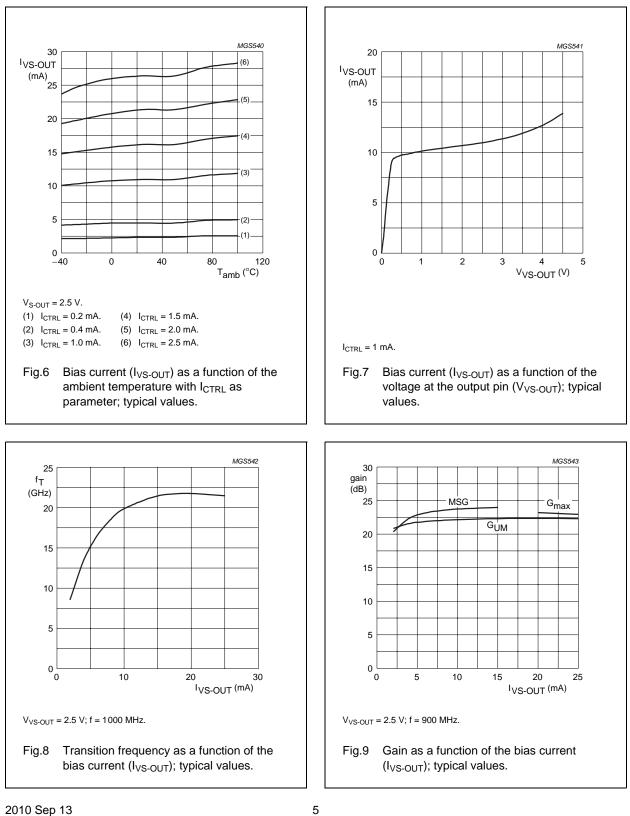
## Note

1. See application note RNR-T45-99-B-0514.

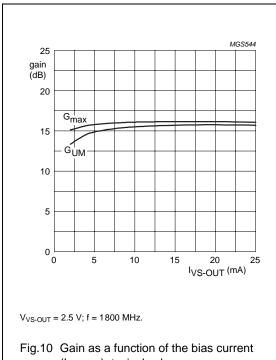
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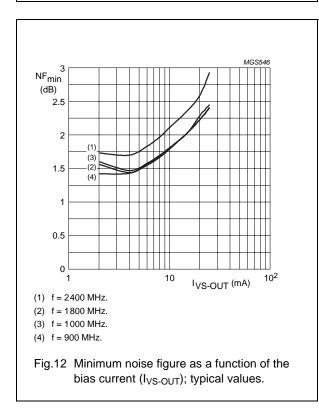
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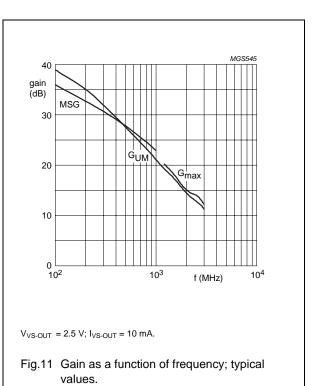


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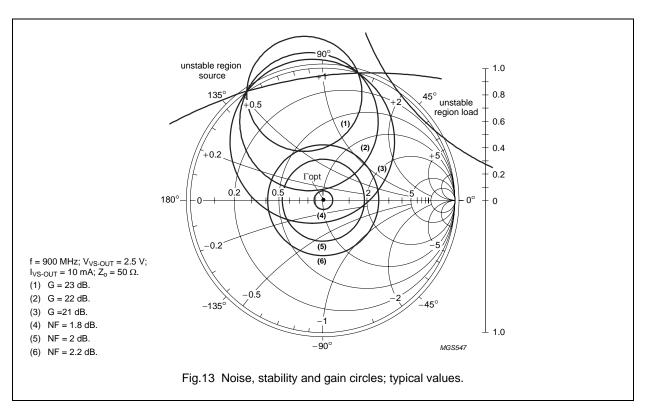


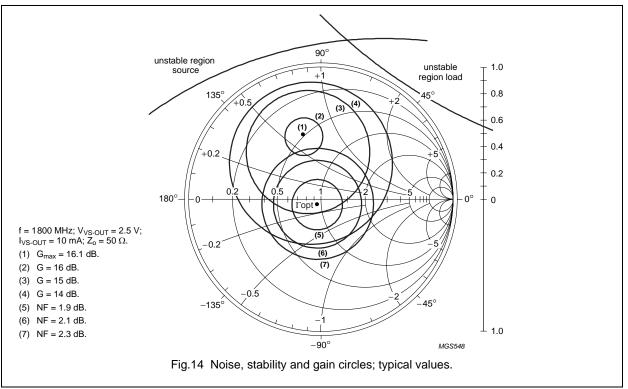
 $(I_{VS-OUT})$ ; typical values.



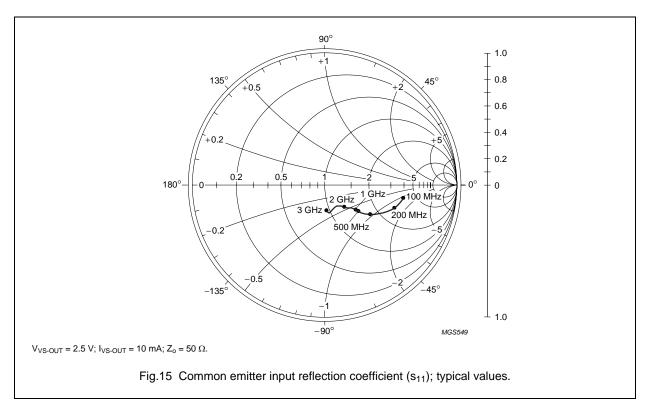


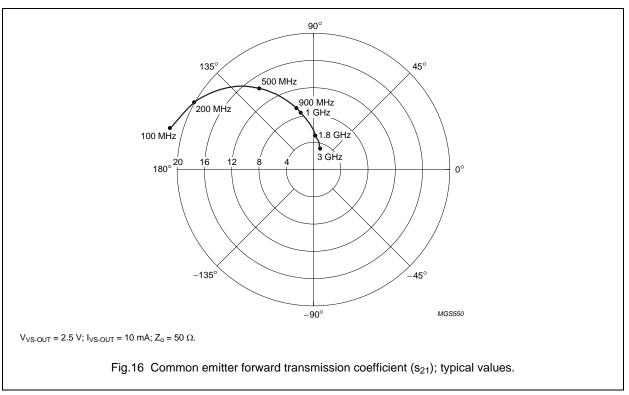
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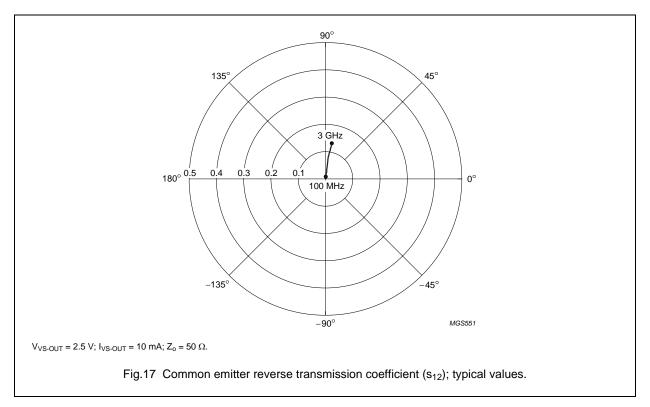


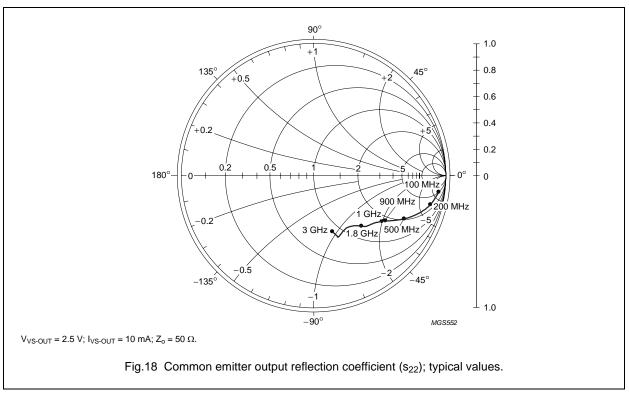
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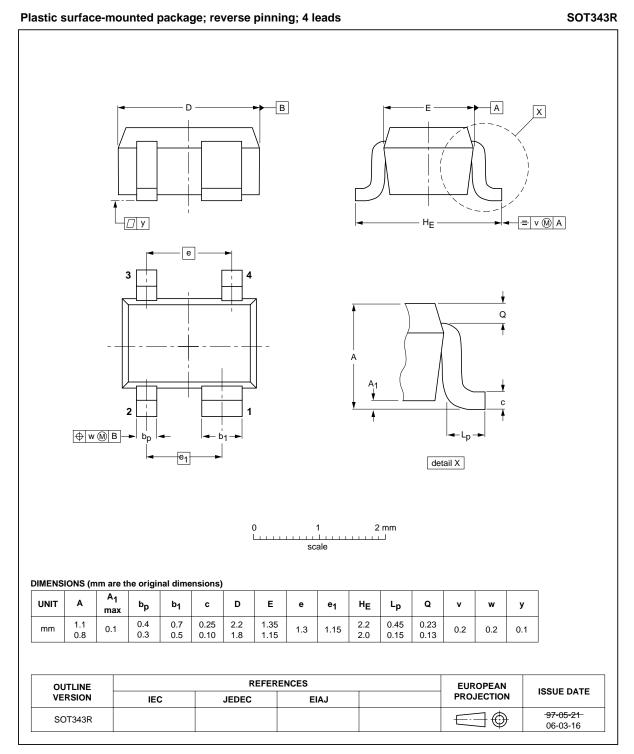




BGA2003

# Silicon MMIC amplifier

#### PACKAGE OUTLINE



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DATA	SHEET	STATUS	
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DOCUMENT STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITION	
Objective data sheet	Development	This document contains data from the objective specification for product development.	
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.	
Product data sheet	Production	This document contains the product specification.	

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## Silicon MMIC amplifier

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